

#### 1K/2K/4K 1.8V Microwire Serial EEPROM

#### Features:

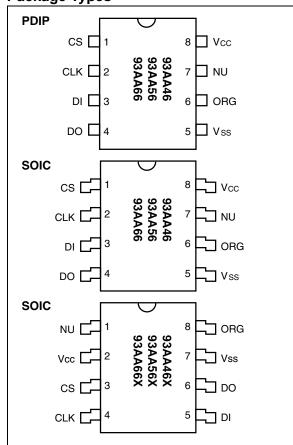
- Single supply with programming operation down to 1.8V
- Low-power CMOS technology:
  - $70 \,\mu\text{A}$  typical active read current at 1.8V
  - 2 μA typical standby current at 1.8V
- ORG pin selectable memory configuration:
  - 128 x 8- or 64 x 16-bit organization (93AA46)
  - 256 x 8- or 128 x 16-bit organization (93AA56)
  - 512 x 8 or 256 x 16-bit organization (93AA66)
- Self-timed erase and write cycles (including auto-erase)
- Automatic ERAL before WRAL
- · Power on/off data protection circuitry
- · Industry standard 3-wire serial I/O
- · Device status signal during erase/write cycles
- · Sequential read function
- 1,000,000 E/W cycles ensured
- Data retention > 200 years
- 8-pin PDIP/SOIC (SOIC in JEDEC and EIAJ standards)
- Temperature ranges supported:

- Commercial (C): 0°C to +70°C - Industrial (I): -40°C to +85°C

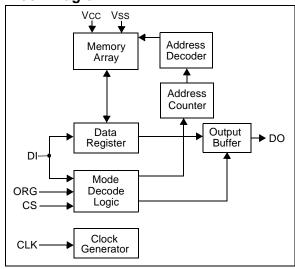
#### **Description:**

The Microchip Technology Inc. 93AA46/56/66 are 1K, 2K and 4K low voltage serial Electrically Erasable PROMs. The device memory is configured as x8 or x16 bits depending on the ORG pin setup. Advanced CMOS technology makes these devices ideal for low power nonvolatile memory applications. The 93AA Series is available in standard 8-pin PDIP and surface mount SOIC packages. The rotated pin-out 93AA46X/56X/66X are offered in the "SN" package only.

#### **Package Types**



#### **Block Diagram**



#### 1.0 ELECTRICAL CHARACTERISTICS

#### Absolute Maximum Ratings(†)

Vcc	7.0\
All inputs and outputs w.r.t. Vss	0.6V to Vcc +1.0V
Storage temperature	65°C to +150°C
Ambient temperature with power applied	40°C to +125°C
Soldering temperature of leads (10 seconds)	+300°C
ESD protection on all pins	4 k\

† NOTICE: Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to Absolute Maximum Rating conditions for extended periods may affect device reliability.

TABLE 1-1: DC AND AC ELECTRICAL CHARACTERISTICS

VCC = +1.8V to +5.5V Commercial (C):  $TA = 0^{\circ}C$  to +70°C Industrial (I):  $TA = -40^{\circ}C$  to +85°C

Parameter	Symbol	Min	Тур	Max	Units	Conditions
High-level input voltage	VIH1	2.0	_	Vcc+1	V	Vcc ≥ 2.7V
	VIH2	0.7 Vcc	_	Vcc+1	V	Vcc < 2.7V
Low-level input voltage	VIL1	-0.3	_	0.8	V	Vcc ≥ 2.7V
	VIL2	-0.3	_	0.2 Vcc	V	Vcc < 2.7V
Low-level output voltage	Vol1	_	_	0.4	V	IOL = 2.1 mA; VCC = 4.5V
	Vol2	_	_	0.2	V	IoL = 100μA; Vcc = 1.8V
High-level output voltage	Vон1	2.4	_	_	V	IOH = -400 $\mu$ A; VCC = 4.5V
	VoH2	Vcc-0.2	_	_	V	IOH = -100 $\mu$ A; VCC = 1.8V
Input leakage current	I⊔	-10	_	10	μΑ	VIN = 0.1V to VCC
Output leakage current	llo	-10		10	μΑ	Vout = 0.1V to Vcc
Pin capacitance (all inputs/outputs)	CIN, COUT	_		7	pF	VIN/VOUT = 0V (Note 1 & 2) TA = +25°C, FCLK = 1 MHz
Operating current	Icc write	_	_	3	mA	FCLK = 2 MHz; VCC=5.5V (Note 2)
	Icc read	_	_	1	mA	FCLK = 2 MHz; VCC = 5.5V
			70	500	μΑ	FCLK = 1 MHz; VCC = 3.0V
Ot a really a summand	lana		70	400	μΑ	FCLK = 1 MHz; VCC = 1.8V
Standby current	Iccs			100 30	μA μA	CLK = CS = 0V; Vcc = 5.5V CLK = CS = 0V; Vcc = 3.0V
			2		μΑ	CLK = CS = 0V; Vcc = 1.8V ORG, DI = Vss or Vcc
Clock frequency	FCLK			2 1	MHz MHz	VCC ≥ 4.5V VCC < 4.5V
Clock high time	Тскн	250			ns	
Clock low time	TCKL	250			ns	
Chip select setup time	Tcss	50			ns	Relative to CLK
Chip select hold time	Тсѕн	0			ns	Relative to CLK
Chip select low time	TCSL	250			ns	
Data input setup time	Tois	100			ns	Relative to CLK
Data input hold time	TDIH	100			ns	Relative to CLK
Data output delay time	TPD			400	ns	CL = 100 pF
Data output disable time	Tcz			100	ns	CL = 100 pF (Note 2)
Status valid time	Tsv			500	ns	CL = 100 pF
Program cycle time	Twc		4	10	ms	Erase/Write mode
	TEC		8	15	ms	ERAL mode (Vcc = 5V ± 10%)
	TwL		16	30	ms	WRAL mode (Vcc = 5V ± 10%)
Endurance	_	1M	_	1M	_	25°C, Vcc = 5.0V, Block mode (Note 3)

**Note 1:** This parameter is tested at  $TA = 25^{\circ}C$  and FCLK = 1 MHz.

<sup>2:</sup> This parameter is periodically sampled and not 100% tested.

<sup>3:</sup> This parameter is not tested but ensured by characterization. For endurance estimates in a specific application, please consult the Total Endurance™ Model which can be obtained from Microchip's web site.

TABLE 1-2: INSTRUCTION SET FOR 93AA46: ORG = 1 (X 16 ORGANIZATION)

Instruction	SB	Opcode	Address	Data In	Data Out	Req. CLK Cycles
READ	1	10	A5 A4 A3 A2 A1 A0	_	D15 - D0	25
EWEN	1	00	1 1 X X X X	_	High-Z	9
ERASE	1	11	A5 A4 A3 A2 A1 A0	_	(RDY/BSY)	9
ERAL	1	00	1 0 X X X X	_	(RDY/BSY)	9
WRITE	1	01	A5 A4 A3 A2 A1 A0	D15 - D0	(RDY/BSY)	25
WRAL	1	00	0 1 X X X X	D15 - D0	(RDY/BSY)	25
EWDS	1	00	0 0 X X X X	_	High-Z	9

TABLE 1-3: INSTRUCTION SET FOR 93AA46: ORG = 0 (X 8 ORGANIZATION)

Instruction	SB	Opcode	Address	Data In	Data Out	Req. CLK Cycles
READ	1	10	A6 A5 A4 A3 A2 A1 A0	_	D7 - D0	18
EWEN	1	00	1 1 X X X X X	_	High-Z	10
ERASE	1	11	A6 A5 A4 A3 A2 A1 A0	_	(RDY/BSY)	10
ERAL	1	00	1 0 X X X X X	_	(RDY/BSY)	10
WRITE	1	01	A6 A5 A4 A3 A2 A1 A0	D7 - D0	(RDY/BSY)	18
WRAL	1	00	0 1 X X X X X	D7 - D0	(RDY/BSY)	18
EWDS	1	00	0 0 X X X X X	_	High-Z	10

TABLE 1-4: INSTRUCTION SET FOR 93AA56: ORG = 1 (X 16 ORGANIZATION)

Instruction	SB	Opcode	Address	Data In	Data Out	Req. CLK Cycles
READ	1	10	X A6 A5 A4 A3 A2 A1 A0	_	D15 - D0	27
EWEN	1	00	1 1 X X X X X X	_	High-Z	11
ERASE	1	11	X A6 A5 A4 A3 A2 A1 A0	_	(RDY/BSY)	11
ERAL	1	00	1 0 X X X X X X	_	(RDY/BSY)	11
WRITE	1	01	X A6 A5 A4 A3 A2 A1 A0	D15 - D0	(RDY/BSY)	27
WRAL	1	00	0 1 X X X X X X	D15 - D0	(RDY/BSY)	27
EWDS	1	00	0 0 X X X X X X	_	High-Z	11

TABLE 1-5: INSTRUCTION SET FOR 93AA56: ORG = 0 (X 8 ORGANIZATION)

Instruction	SB	Opcode	Address	Data In	Data Out	Req. CLK Cycles
READ	1	10	X A7 A6 A5 A4 A3 A2 A1 A0	-	D7 - D0	20
EWEN	1	00	1 1 X X X X X X X	_	High-Z	12
ERASE	1	11	X A7 A6 A5 A4 A3 A2 A1 A0	_	(RDY/BSY)	12
ERAL	1	00	1 0 X X X X X X X	_	(RDY/BSY)	12
WRITE	1	01	X A7 A6 A5 A4 A3 A2 A1 A0	D7 - D0	(RDY/BSY)	20
WRAL	1	00	0 1 X X X X X X X	D7 - D0	(RDY/BSY)	20
EWDS	1	00	0 0 X X X X X X X		High-Z	12

TABLE 1-6: INSTRUCTION SET FOR 93AA66: ORG = 1 (X 16 ORGANIZATION)

					· .		
Instruction	SB	Opcode	Address	Data In	Data Out	Req. CLK Cycles	
READ	1	10	A7 A6 A5 A4 A3 A2 A1 A0	_	D15 - D0	27	
EWEN	1	00	1 1 X X X X X X	_	High-Z	11	
ERASE	1	11	A7 A6 A5 A4 A3 A2 A1 A0	_	(RDY/BSY)	11	
ERAL	1	00	1 0 X X X X X X	_	(RDY/BSY)	11	
WRITE	1	01	A7 A6 A5 A4 A3 A2 A1 A0	D15 - D0	(RDY/BSY)	27	
WRAL	1	00	0 1 X X X X X X	D15 - D0	(RDY/BSY)	27	
EWDS	1	00	0 0 X X X X X X	_	High-Z	11	

TABLE 1-7: INSTRUCTION SET FOR 93AA66: ORG = 0 (X 8 ORGANIZATION)

Instruction	SB	Opcode	Address	Data In	Data Out	Req. CLK Cycles
READ	1	10	A8 A7 A6 A5 A4 A3 A2 A1 A0	_	D7 - D0	20
EWEN	1	00	1 1 X X X X X X X	_	High-Z	12
ERASE	1	11	A8 A7 A6 A5 A4 A3 A2 A1 A0	_	(RDY/BSY)	12
ERAL	1	00	1 0 X X X X X X X	_	(RDY/BSY)	12
WRITE	1	01	A8 A7 A6 A5 A4 A3 A2 A1 A0	D7 - D0	(RDY/BSY)	20
WRAL	1	00	0 1 X X X X X X X	D7 - D0	(RDY/BSY)	20
EWDS	1	00	0 0 X X X X X X X	_	High-Z	12

#### 2.0 FUNCTIONAL DESCRIPTION

When the ORG pin is connected to VCC, the (x16) organization is selected. When it is connected to ground, the (x8) organization is selected. Instructions, addresses and write data are clocked into the DI pin on the rising edge of the clock (CLK). The DO pin is normally held in a high-Z state except when reading data from the device, or when checking the Ready/Busy status during a programming operation. The Ready/Busy status can be verified during an erase/write operation by polling the DO pin; DO low indicates that programming is still in progress, while DO high indicates the device is ready. The DO will enter the high-Z state on the falling edge of the CS.

#### 2.1 Start Condition

The Start bit is detected by the device if CS and DI are both high with respect to the positive edge of CLK for the first time.

Before a Start condition is detected, CS, CLK and DI may change in any combination (except to that of a Start condition), without resulting in any device operation (read, write, erase, EWEN, EWDS, ERAL, and WRAL). As soon as CS is high, the device is no longer in the Standby mode.

An instruction following a Start condition will only be executed if the required amount of opcode, address and data bits for any particular instruction is clocked in.

After execution of an instruction (i.e., clock in or out of the last required address or data bit) CLK and DI become "don't care" bits until a new Start condition is detected.

#### 2.2 DI/DO

It is possible to connect the Data In and Data Out pins together. However, with this configuration it is possible for a "bus conflict" to occur during the "dummy zero" that precedes the read operation, if A0 is a logic high level. Under such a condition the voltage level seen at Data Out is undefined and will depend upon the relative impedances of Data Out and the signal source driving A0. The higher the current sourcing capability of A0, the higher the voltage at the Data Out pin.

#### 2.3 Data Protection

During power-up, all programming modes of operation are inhibited until Vcc has reached a level greater than 1.4V. During power-down, the source data protection circuitry acts to inhibit all programming modes when Vcc has fallen below 1.4V at nominal conditions.

The EWEN and EWDS commands give additional protection against accidentally programming during normal operation.

After power-up, the device is automatically in the EWDS mode. Therefore, an EWEN instruction must be performed before any ERASE or WRITE instruction can be executed.

#### 2.4 Read

The READ instruction outputs the serial data of the addressed memory location on the DO pin. A dummy zero bit precedes the 16-bit (x16 organization) or 8 bit (x8 organization) output string. The output data bits will toggle on the rising edge of the CLK and are stable after the specified time delay (TPD). Sequential read is possible when CS is held high. The memory data will automatically cycle to the next register and output sequentially.

## 2.5 Erase/Write Enable and Disable (EWEN, EWDS)

The 93AA46/56/66 power up in the Erase/Write Disable (EWDS) state. All programming modes must be preceded by an Erase/Write Enable (EWEN) instruction. Once the EWEN instruction is executed, programming remains enabled until an EWDS instruction is executed or VCC is removed from the device. To protect against accidental data disturb, the EWDS instruction can be used to disable all erase/write functions and should follow all programming operations. Execution of a READ instruction is independent of both the EWEN and EWDS instructions.

#### 2.6 Erase

The ERASE instruction forces all data bits of the specified address to the logical "1" state. CS is brought low following the loading of the last address bit. This falling edge of the CS pin initiates the self-timed programming cycle.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (Tcsl). DO at logical "0" indicates that programming is still in progress. DO at logical "1" indicates that the register at the specified address has been erased and the device is ready for another instruction.

The erase cycle takes 4 ms per word typical.

#### 2.7 Write

The WRITE instruction is followed by 16 bits (or by 8 bits) of data which are written into the specified address. After the last data bit is put on the DI pin, CS must be brought low before the next rising edge of the CLK clock. This falling edge of CS initiates the self-timed auto-erase and programming cycle.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TCSL) and before the entire write cycle is complete. DO at logical "0" indicates that programming is still in progress. DO at logical "1" indicates that the register at the specified address has been written with the data specified and the device is ready for another instruction.

The write cycle takes 4 ms per word typical.

#### 2.8 Erase All (ERAL)

The ERAL instruction will erase the entire memory array to the logical "1" state. The ERAL cycle is identical to the erase cycle except for the different opcode. The ERAL cycle is completely self-timed and commences at the falling edge of the CS. Clocking of the CLK pin is not necessary after the device has entered the Self Clocking mode. The ERAL instruction is ensured at 5V  $\pm$  10%.

The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TcsL) and before the entire write cycle is complete.

The ERAL cycle takes (8 ms typical).

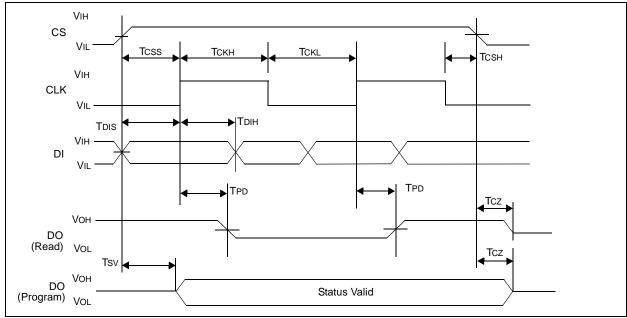
#### 2.9 Write All (WRAL)

The WRAL instruction will write the entire memory array with the data specified in the command. The WRAL cycle is completely self-timed and commences at the falling edge of the CS. Clocking of the CLK pin is not necessary after the device has entered the Self Clocking mode. The WRAL command does include an automatic ERAL cycle for the device. Therefore, the WRAL instruction does not require an ERAL instruction but the chip must be in the EWEN status. The WRAL instruction is ensured at  $5\,\mathrm{V}\pm10\%$ .

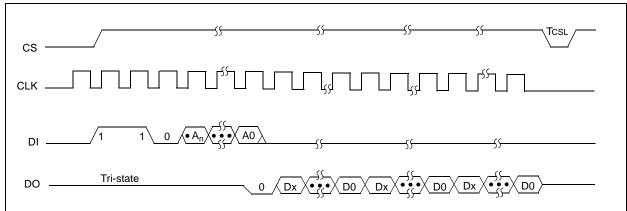
The DO pin indicates the Ready/Busy status of the device if CS is brought high after a minimum of 250 ns low (TcsL).

The WRAL cycle takes 16 ms typical.

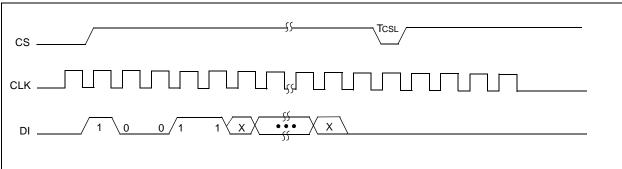
FIGURE 2-1: SYNCHRONOUS DATA TIMING



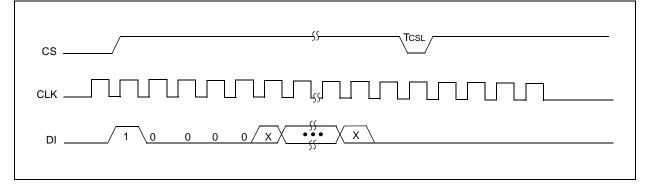
#### FIGURE 2-2: READ TIMING



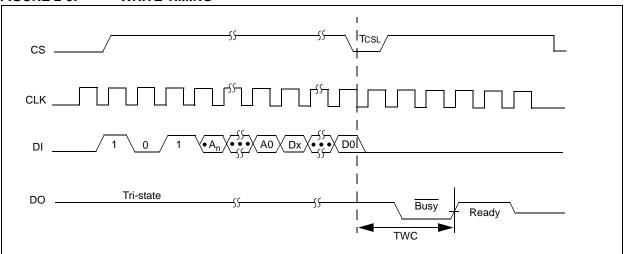
#### FIGURE 2-3: EWEN TIMING



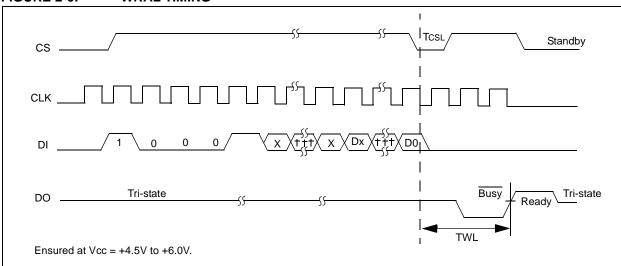
#### FIGURE 2-4: EWDS TIMING



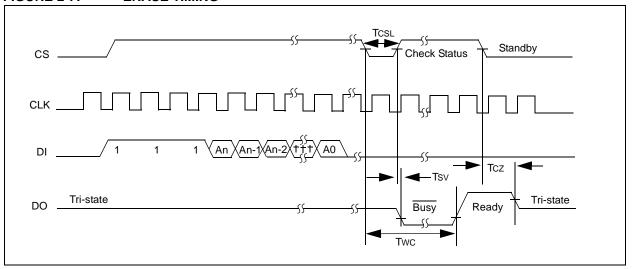
#### FIGURE 2-5: WRITE TIMING



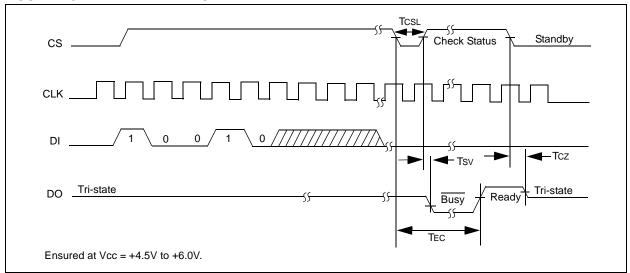
#### FIGURE 2-6: WRAL TIMING



#### FIGURE 2-7: ERASE TIMING







#### 3.0 PIN DESCRIPTION

TABLE 3-1: PIN FUNCTION TABLE

Name	Function
CS	Chip Select
CLK	Serial Data Clock
DI	Serial Data Input
DO	Serial Data Output
Vss	Ground
ORG	Memory Configuration
NU	Not Utilized
Vcc	Power Supply

#### 3.1 Chip Select (CS)

A high level selects the device. A low level deselects the device and forces it into Standby mode. However, a programming cycle which is already initiated and/or in progress will be completed, regardless of the CS input signal. If CS is brought low during a program cycle, the device will go into Standby mode as soon as the programming cycle is completed.

CS must be low for 250 ns minimum (TCSL) between consecutive instructions. If CS is low, the internal control logic is held in a Reset status.

#### 3.2 Serial Clock (CLK)

The Serial Clock is used to synchronize the communication between a master device and the 93AAXX. Opcode, address, and data bits are clocked in on the positive edge of CLK. Data bits are also clocked out on the positive edge of CLK.

CLK can be stopped anywhere in the transmission sequence (at high or low level) and can be continued anytime with respect to clock high time (TCKH) and clock low time (TCKL). This gives the controlling master freedom in preparing opcode, address and data.

CLK is a "don't care" if CS is low (device deselected). If CS is high, but Start condition has not been detected, any number of clock cycles can be received by the device without changing its status (i.e., waiting for Start condition).

CLK cycles are not required during the self-timed write (i.e., auto erase/write) cycle.

After detection of a Start condition the specified number of clock cycles (respectively low-to-high transitions of CLK) must be provided. These clock cycles are required to clock in all required opcode, address and data bits before an instruction is executed (see instruction set truth table). CLK and DI then become "don't care" inputs waiting for a new Start condition to be detected.

Note:	CS must go low between consecutive
	instructions.

#### 3.3 Data In (DI)

Data In is used to clock in a Start bit, opcode, address and data synchronously with the CLK input.

#### 3.4 Data Out (DO)

Data Out is used in the Read mode to output data synchronously with the CLK input (TPD after the positive edge of CLK).

This pin also provides Ready/Busy status information during erase and write cycles. Ready/Busy status information is available on the DO pin if CS is brought high after being low for minimum chip select low time (TCSL) and an erase or write operation has been initiated.

The status signal is not available on DO, if CS is held low or high during the entire write or erase cycle. In all other cases DO is in the High-Z mode. If status is checked after the write/erase cycle, a pull-up resistor on DO is required to read the Ready signal.

#### 3.5 Organization (ORG)

When ORG is connected to Vcc, the (x16) memory organization is selected. When ORG is tied to Vss, the (x8) memory organization is selected. ORG can only be floated for clock speeds of 1MHz or less for the (x16) memory organization. For clock speeds greater than 1 MHz, ORG must be tied to Vcc or Vss.

#### 4.0 PACKAGING INFORMATION

#### 4.1 Package Marking Information

8-Lead PDIP



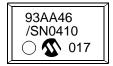
#### Example



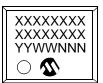
8-Lead SOIC (.150")



#### Example



8-Lead SOIC (.208")



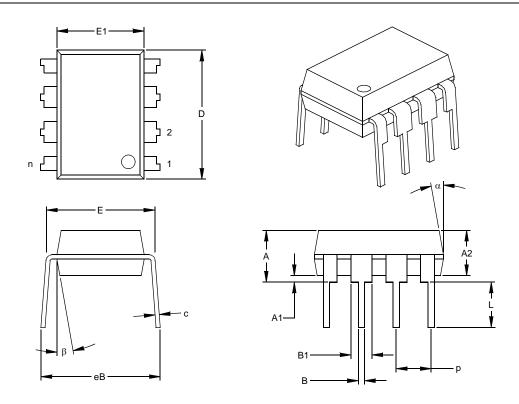
#### Example



#### 8-Lead Plastic Dual In-line (P) - 300 mil Body (PDIP)

Note:

For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES*			MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX	MIN	NOM	MAX	
Number of Pins	n		8			8		
Pitch	р		.100			2.54		
Top to Seating Plane	Α	.140	.155	.170	3.56	3.94	4.32	
Molded Package Thickness	A2	.115	.130	.145	2.92	3.30	3.68	
Base to Seating Plane	A1	.015			0.38			
Shoulder to Shoulder Width	Е	.300	.313	.325	7.62	7.94	8.26	
Molded Package Width	E1	.240	.250	.260	6.10	6.35	6.60	
Overall Length	D	.360	.373	.385	9.14	9.46	9.78	
Tip to Seating Plane	L	.125	.130	.135	3.18	3.30	3.43	
Lead Thickness	С	.008	.012	.015	0.20	0.29	0.38	
Upper Lead Width	B1	.045	.058	.070	1.14	1.46	1.78	
Lower Lead Width	В	.014	.018	.022	0.36	0.46	0.56	
Overall Row Spacing §	eB	.310	.370	.430	7.87	9.40	10.92	
Mold Draft Angle Top	α	5	10	15	5	10	15	
Mold Draft Angle Bottom	β	5	10	15	5	10	15	

<sup>\*</sup> Controlling Parameter

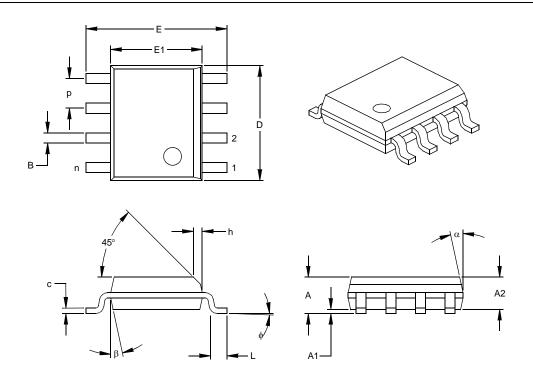
Notes:
Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

JEDEC Equivalent: MS-001
Drawing No. C04-018

<sup>§</sup> Significant Characteristic

#### 8-Lead Plastic Small Outline (SN) - Narrow, 150 mil Body (SOIC)

Note: For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units		INCHES*		N	IILLIMETERS	LIMETERS	
Dimension	MIN	NOM	MAX	MIN	NOM	MAX		
Number of Pins	n		8			8		
Pitch	р		.050			1.27		
Overall Height	Α	.053	.061	.069	1.35	1.55	1.75	
Molded Package Thickness	A2	.052	.056	.061	1.32	1.42	1.55	
Standoff §	A1	.004	.007	.010	0.10	0.18	0.25	
Overall Width	Е	.228	.237	.244	5.79	6.02	6.20	
Molded Package Width	E1	.146	.154	.157	3.71	3.91	3.99	
Overall Length	D	.189	.193	.197	4.80	4.90	5.00	
Chamfer Distance	h	.010	.015	.020	0.25	0.38	0.51	
Foot Length	L	.019	.025	.030	0.48	0.62	0.76	
Foot Angle	ф	0	4	8	0	4	8	
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25	
Lead Width	В	.013	.017	.020	0.33	0.42	0.51	
Mold Draft Angle Top	α	0	12	15	0	12	15	
Mold Draft Angle Bottom	β	0	12	15	0	12	15	

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed

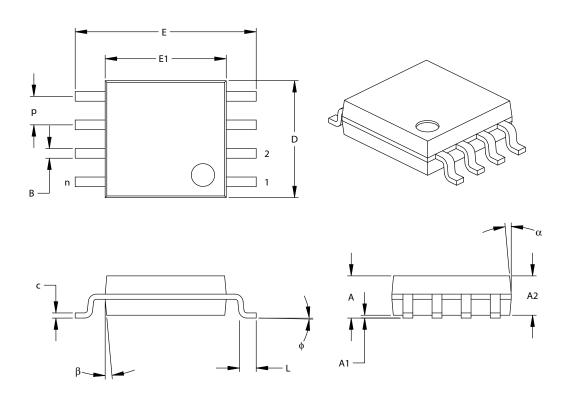
.010" (0.254mm) per side. JEDEC Equivalent: MS-012 Drawing No. C04-057

<sup>\*</sup> Controlling Parameter § Significant Characteristic

#### 8-Lead Plastic Small Outline (SM) - Medium, 208 mil Body (SOIJ)

(JEITA/EIAJ Standard, Formerly called SOIC)

**Note:** For the most current package drawings, please see the Microchip Packaging Specification located at http://www.microchip.com/packaging



	Units	INCHES*			MILLIMETERS		
Dimension Limi	ts	MIN	NOM	MAX	MIN	NOM	MAX
Number of Pins	n	8		8			
Pitch	р		.050			1.27	
Overall Height	Α	.070	.075	.080	1.78	1.97	2.03
Molded Package Thickness	A2	.069	.074	.078	1.75	1.88	1.98
Standoff	A1	.002	.005	.010	0.05	0.13	0.25
Overall Width	E	.300	.313	.325	7.62	7.95	8.26
Molded Package Width	E1	.201	.208	.212	5.11	5.28	5.38
Overall Length	D	.202	.205	.210	5.13	5.21	5.33
Foot Length	L	.020	.025	.030	0.51	0.64	0.76
Foot Angle	ф	0	4	8	0	4	8
Lead Thickness	С	.008	.009	.010	0.20	0.23	0.25
Lead Width	В	.014	.017	.020	0.36	0.43	0.51
Mold Draft Angle Top	α	0	12	15	0	12	15
Mold Draft Angle Bottom	β	0	12	15	0	12	15

\*Controlling Parameter

Notes:

Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" (0.254mm) per side.

Drawing No. C04-056

#### APPENDIX A: REVISION HISTORY

#### **Revision J**

Added note to page 1 header (Not recommended for new designs).

Added Section 4.0: Package Marking Information.

Added On-line Support page.

Updated document format.

#### Revision K

Added a note to each package outline drawing.

#### THE MICROCHIP WEB SITE

Microchip provides online support via our WWW site at www.microchip.com. This web site is used as a means to make files and information easily available to customers. Accessible by using your favorite Internet browser, the web site contains the following information:

- Product Support Data sheets and errata, application notes and sample programs, design resources, user's guides and hardware support documents, latest software releases and archived software
- General Technical Support Frequently Asked Questions (FAQ), technical support requests, online discussion groups, Microchip consultant program member listing
- Business of Microchip Product selector and ordering guides, latest Microchip press releases, listing of seminars and events, listings of Microchip sales offices, distributors and factory representatives

## CUSTOMER CHANGE NOTIFICATION SERVICE

Microchip's customer notification service helps keep customers current on Microchip products. Subscribers will receive e-mail notification whenever there are changes, updates, revisions or errata related to a specified product family or development tool of interest.

To register, access the Microchip web site at www.microchip.com. Under "Support", click on "Customer Change Notification" and follow the registration instructions.

#### CUSTOMER SUPPORT

Users of Microchip products can receive assistance through several channels:

- · Distributor or Representative
- · Local Sales Office
- Field Application Engineer (FAE)
- · Technical Support

Customers should contact their distributor, representative or field application engineer (FAE) for support. Local sales offices are also available to help customers. A listing of sales offices and locations is included in the back of this document.

Technical support is available through the web site at: http://microchip.com/support

#### READER RESPONSE

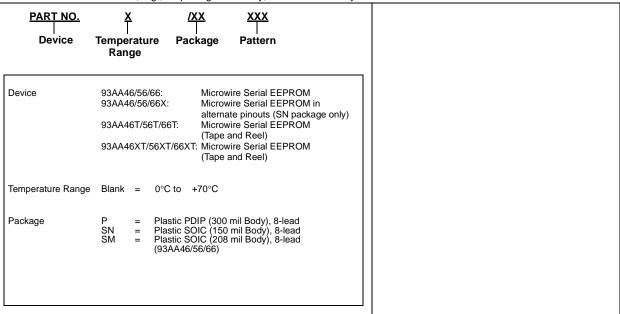
It is our intention to provide you with the best documentation possible to ensure successful use of your Microchip product. If you wish to provide your comments on organization, clarity, subject matter, and ways in which our documentation can better serve you, please FAX your comments to the Technical Publications Manager at (480) 792-4150.

Please list the following information, and use this outline to provide us with your comments about this document.

TO: RE:	Technical Publications Manager Reader Response	Total Pages Sent				
From	: Name					
	Company					
	Address					
	City / State / ZIP / Country					
	Telephone: ()	FAX: (				
Appli	cation (optional):					
Woul	d you like a reply?YN					
Devic	ce: 93AA46/56/66	Literature Number: DS20067K				
Ques	tions:					
1. V	What are the best features of this document?					
_						
2. H	low does this document meet your hardware and so	ftware development needs?				
-						
3. D	Do you find the organization of this document easy to follow? If not, why?					
_						
_						
4. V	What additions to the document do you think would e	nnance the structure and subject?				
_						
5. V	What deletions from the document could be made without affecting the overall usefulness?					
_						
6. Is	s there any incorrect or misleading information (what	and where)?				
_						
7. H	low would you improve this document?					
_						

#### PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.



#### **Sales and Support**

#### **Data Sheets**

Products supported by a preliminary Data Sheet may have an errata sheet describing minor operational differences and recommended workarounds. To determine if an errata sheet exists for a particular device, please contact one of the following:

- 1. Your local Microchip sales office
- 2. The Microchip Worldwide Site (www.microchip.com)

Please specify which device, revision of silicon and Data Sheet (include Literature #) you are using.

#### **New Customer Notification System**

Register on our web site (www.microchip.com/cn) to receive the most current information on our products.

## **PIC18FXXXX**

NOTES:

#### Note the following details of the code protection feature on Microchip devices:

- Microchip products meet the specification contained in their particular Microchip Data Sheet.
- Microchip believes that its family of products is one of the most secure families of its kind on the market today, when used in the
  intended manner and under normal conditions.
- There are dishonest and possibly illegal methods used to breach the code protection feature. All of these methods, to our knowledge, require using the Microchip products in a manner outside the operating specifications contained in Microchip's Data Sheets. Most likely, the person doing so is engaged in theft of intellectual property.
- Microchip is willing to work with the customer who is concerned about the integrity of their code.
- Neither Microchip nor any other semiconductor manufacturer can guarantee the security of their code. Code protection does not mean that we are guaranteeing the product as "unbreakable."

Code protection is constantly evolving. We at Microchip are committed to continuously improving the code protection features of our products. Attempts to break Microchip's code protection feature may be a violation of the Digital Millennium Copyright Act. If such acts allow unauthorized access to your software or other copyrighted work, you may have a right to sue for relief under that Act.

Information contained in this publication regarding device applications and the like is provided only for your convenience and may be superseded by updates. It is your responsibility to ensure that your application meets with your specifications. MICROCHIP MAKES NO REPRESENTATIONS OR WARRANTIES OF ANY KIND WHETHER EXPRESS OR IMPLIED, WRITTEN OR ORAL, STATUTORY OR OTHERWISE, RELATED TO THE INFORMATION, INCLUDING BUT NOT LIMITED TO ITS CONDITION, QUALITY, PERFORMANCE, MERCHANTABILITY OR FITNESS FOR PURPOSE. Microchip disclaims all liability arising from this information and its use. Use of Microchip devices in life support and/or safety applications is entirely at the buyer's risk, and the buyer agrees to defend, indemnify and hold harmless Microchip from any and all damages, claims, suits, or expenses resulting from such use. No licenses are conveyed, implicitly or otherwise, under any Microchip intellectual property rights.

# QUALITY MANAGEMENT SYSTEM CERTIFIED BY DNV = ISO/TS 16949=

#### **Trademarks**

The Microchip name and logo, the Microchip logo, dsPIC, FlashFlex, KEELOQ, KEELOQ logo, MPLAB, PIC, PICmicro, PICSTART, PIC<sup>32</sup> logo, rfPIC, SST, SST Logo, SuperFlash and UNI/O are registered trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

FilterLab, Hampshire, HI-TECH C, Linear Active Thermistor, MTP, SEEVAL and The Embedded Control Solutions Company are registered trademarks of Microchip Technology Incorporated in the U.S.A.

Silicon Storage Technology is a registered trademark of Microchip Technology Inc. in other countries.

Analog-for-the-Digital Age, Application Maestro, BodyCom, chipKIT, chipKIT logo, CodeGuard, dsPICDEM, dsPICDEM.net, dsPICworks, dsSPEAK, ECAN, ECONOMONITOR, FanSense, HI-TIDE, In-Circuit Serial Programming, ICSP, Mindi, MiWi, MPASM, MPF, MPLAB Certified logo, MPLIB, MPLINK, mTouch, Omniscient Code Generation, PICC, PICC-18, PICDEM, PICDEM.net, PICkit, PICtail, REAL ICE, rfLAB, Select Mode, SQI, Serial Quad I/O, Total Endurance, TSHARC, UniWinDriver, WiperLock, ZENA and Z-Scale are trademarks of Microchip Technology Incorporated in the U.S.A. and other countries.

SQTP is a service mark of Microchip Technology Incorporated in the U.S.A.

GestIC and ULPP are registered trademarks of Microchip Technology Germany II GmbH & Co. & KG, a subsidiary of Microchip Technology Inc., in other countries.

All other trademarks mentioned herein are property of their respective companies.

© 1998-2012, Microchip Technology Incorporated, Printed in the U.S.A., All Rights Reserved.

Printed on recycled paper.

ISBN: 9781620767320

Microchip received ISO/TS-16949:2009 certification for its worldwide headquarters, design and wafer fabrication facilities in Chandler and Tempe, Arizona; Gresham, Oregon and design centers in California and India. The Company's quality system processes and procedures are for its PIC® MCUs and dsPIC® DSCs, KEELOQ® code hopping devices, Serial EEPROMs, microperipherals, nonvolatile memory and analog products. In addition, Microchip's quality system for the design and manufacture of development systems is ISO 9001:2000 certified.



## **Worldwide Sales and Service**

#### **AMERICAS**

**Corporate Office** 

2355 West Chandler Blvd. Chandler, AZ 85224-6199 Tel: 480-792-7200 Fax: 480-792-7277 Technical Support:

http://www.microchip.com/

support

Web Address: www.microchip.com

Atlanta

Duluth, GA Tel: 678-957-9614 Fax: 678-957-1455

Boston

Westborough, MA Tel: 774-760-0087 Fax: 774-760-0088

Chicago Itasca, IL

Tel: 630-285-0071 Fax: 630-285-0075

Cleveland

Independence, OH Tel: 216-447-0464 Fax: 216-447-0643

**Dallas** 

Addison, TX Tel: 972-818-7423 Fax: 972-818-2924

Detroit

Farmington Hills, MI Tel: 248-538-2250 Fax: 248-538-2260

Indianapolis

Noblesville, IN Tel: 317-773-8323 Fax: 317-773-5453

Los Angeles

Mission Viejo, CA Tel: 949-462-9523 Fax: 949-462-9608

Santa Clara

Santa Clara, CA Tel: 408-961-6444 Fax: 408-961-6445

Toronto

Mississauga, Ontario,

Canada

Tel: 905-673-0699 Fax: 905-673-6509

#### ASIA/PACIFIC

**Asia Pacific Office** 

Suites 3707-14, 37th Floor Tower 6, The Gateway Harbour City, Kowloon Hong Kong

Tel: 852-2401-1200 Fax: 852-2401-3431

Australia - Sydney

Tel: 61-2-9868-6733 Fax: 61-2-9868-6755

China - Beijing

Tel: 86-10-8569-7000 Fax: 86-10-8528-2104

China - Chengdu

Tel: 86-28-8665-5511 Fax: 86-28-8665-7889

China - Chongqing

Tel: 86-23-8980-9588 Fax: 86-23-8980-9500

China - Hangzhou

Tel: 86-571-2819-3187 Fax: 86-571-2819-3189

China - Hong Kong SAR

Tel: 852-2401-1200 Fax: 852-2401-3431

China - Nanjing

Tel: 86-25-8473-2460 Fax: 86-25-8473-2470

China - Qingdao

Tel: 86-532-8502-7355 Fax: 86-532-8502-7205

China - Shanghai

Tel: 86-21-5407-5533 Fax: 86-21-5407-5066

China - Shenyang

Tel: 86-24-2334-2829 Fax: 86-24-2334-2393

China - Shenzhen

Tel: 86-755-8203-2660 Fax: 86-755-8203-1760

China - Wuhan

Tel: 86-27-5980-5300 Fax: 86-27-5980-5118

China - Xian

Tel: 86-29-8833-7252 Fax: 86-29-8833-7256

China - Xiamen

Tel: 86-592-2388138 Fax: 86-592-2388130

China - Zhuhai

Tel: 86-756-3210040 Fax: 86-756-3210049

#### ASIA/PACIFIC

India - Bangalore

Tel: 91-80-3090-4444 Fax: 91-80-3090-4123

India - New Delhi

Tel: 91-11-4160-8631 Fax: 91-11-4160-8632

India - Pune

Tel: 91-20-2566-1512 Fax: 91-20-2566-1513

Japan - Osaka

Tel: 81-66-152-7160 Fax: 81-66-152-9310

Japan - Yokohama

Tel: 81-45-471- 6166 Fax: 81-45-471-6122

Korea - Daegu

Tel: 82-53-744-4301 Fax: 82-53-744-4302

Korea - Seoul

Tel: 82-2-554-7200 Fax: 82-2-558-5932 or 82-2-558-5934

Malaysia - Kuala Lumpur

Tel: 60-3-6201-9857 Fax: 60-3-6201-9859

Malaysia - Penang Tel: 60-4-227-8870

Fax: 60-4-227-4068

Philippines - Manila

Tel: 63-2-634-9065 Fax: 63-2-634-9069

Singapore

Tel: 65-6334-8870 Fax: 65-6334-8850

Taiwan - Hsin Chu

Tel: 886-3-5778-366 Fax: 886-3-5770-955

Taiwan - Kaohsiung

Tel: 886-7-213-7828 Fax: 886-7-330-9305

Taiwan - Taipei

Tel: 886-2-2508-8600 Fax: 886-2-2508-0102

Thailand - Bangkok Tel: 66-2-694-1351

Fax: 66-2-694-1350

#### **EUROPE**

Austria - Wels

Tel: 43-7242-2244-39 Fax: 43-7242-2244-393 Denmark - Copenhagen

Tel: 45-4450-2828

Tel: 45-4450-2828 Fax: 45-4485-2829

France - Paris

Tel: 33-1-69-53-63-20 Fax: 33-1-69-30-90-79

**Germany - Munich** 

Tel: 49-89-627-144-0 Fax: 49-89-627-144-44

Italy - Milan

Tel: 39-0331-742611 Fax: 39-0331-466781

Netherlands - Drunen

Tel: 31-416-690399 Fax: 31-416-690340

Spain - Madrid

Tel: 34-91-708-08-90 Fax: 34-91-708-08-91

**UK - Wokingham** Tel: 44-118-921-5869 Fax: 44-118-921-5820

10/26/12

## **X-ON Electronics**

Largest Supplier of Electrical and Electronic Components

Click to view similar products for EEPROM category:

Click to view products by Microchip manufacturer:

Other Similar products are found below:

M29F040-70K6 718278CB 718620G 444358RB 444362FB BR93C46-WMN7TP EEROMH CAT25320YIGT-KK LE24C162-R-E 5962-8751409YA BR9016AF-WE2 LE2464DXATBG CAS93C66VP2I-GT3 W60002FT20T CAT24S128C4UTR ZD24C64B-SSGMA0 BL24C04F-RRRC S-25C040A0I-I8T1U AT24C256BY7-YH-T M24C64-DFCT6TPK BR24C21FJ-E2 BR24G02FVJ-3GTE2 BR24L16FJ-WE2 BR24L16FJ-WE2 BR24S16FJ-WE2 BR24S256F-WE2 BR93L56RFV-WE2 BR93L66F-WE2 BR93L76RFV-WE2 CAT24C64C4CTR CHL24C32WEGT3 AT28HC256E-12SU-T AT93C46DY6-YH-T BR24T02FVT-WSGE2 M35B32-WMN6TP M24C64-FMC6TG M24C08-WDW6TP CAT25080VP2IGTQH CAT25020ZIGT-QP CAT24C01VP2I-GT3 CAT93C76BZI-GT3 CAT64LC40WI-T3 CAT25256HU4E-GT3 CAT25128VP2I-GT3 CAT25040VP2I-GT3 CAT25020VP2I-GT3 CAT24C16ZI-G CAT24C05LI-G CAT24C01ZI-G CAT24C05WI-G